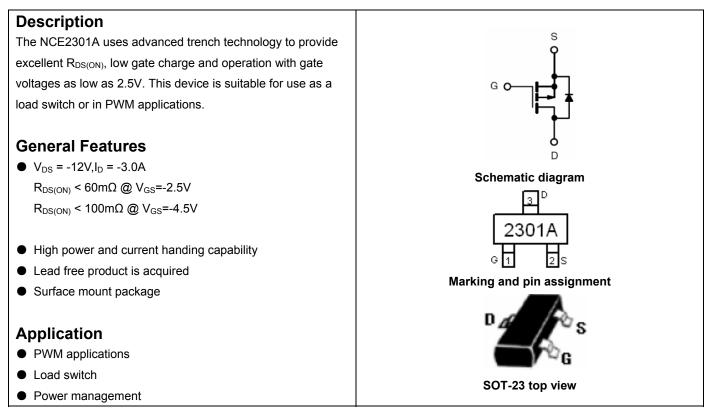


NCE P-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|----------|----------------|-----------|------------|------------|
| 2301A | NCE2301A | SOT-23 | Ø180mm | 8 mm | 3000 units |

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|--|----------------------------------|------------|------|
| Drain-Source Voltage | Vds | -12 | V |
| Gate-Source Voltage | Vgs | ±12 | V |
| Drain Current-Continuous | I _D | -3.0 | А |
| Drain Current -Pulsed (Note 1) | I _{DM} | -15 | А |
| Maximum Power Dissipation | PD | 1 | W |
| Operating Junction and Storage Temperature Range | T _J ,T _{STG} | -55 To 150 | °C |

Thermal Characteristic

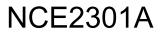
| Thermal Resistance, Junction-to-Ambient (Note 2) | R _{θJA} | 125 | °C /W |
|--|------------------|-----|--------------|
|--|------------------|-----|--------------|

Electrical Characteristics (T_A=25[°]C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|---------------------------------|-------------------|--|-----|-----|-----|------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =-250µA | -12 | - | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V_{DS} =-12V, V_{GS} =0V | - | - | -1 | μA |







| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|---------------------|--|------|------|------|------|
| Gate-Body Leakage Current | I _{GSS} | V_{GS} =±12V, V_{DS} =0V | - | - | ±100 | nA |
| On Characteristics (Note 3) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=-250\mu A$ | -0.4 | -0.7 | -1 | V |
| Drain Course On State Desistance | R _{DS(ON)} | V _{GS} =-4.5V, I _D =-2.5A | - | 42 | 60 | mΩ |
| Drain-Source On-State Resistance | | V_{GS} =-2.5V, I_D =-2A | - | 47 | 100 | mΩ |
| Forward Transconductance | g fs | V _{DS} =-5V,I _D =-2A | 5 | - | - | S |
| Dynamic Characteristics (Note4) | | | • | | | |
| Input Capacitance | C _{lss} | (1 - 40)(1)(-0)(| - | 405 | - | PF |
| Output Capacitance | C _{oss} | V _{DS} =-10V,V _{GS} =0V, F=1.0MHz | - | 112 | - | PF |
| Reverse Transfer Capacitance | C _{rss} | | - | 89 | - | PF |
| Switching Characteristics (Note 4) | | | | | | |
| Turn-on Delay Time | t _{d(on)} | | - | 11 | - | nS |
| Turn-on Rise Time | tr | V _{DD} =-10V, R _L =2.9Ω | - | 35 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | V_{GS} =-4.5V, R_{GEN} =10 Ω | - | 30 | - | nS |
| Turn-Off Fall Time | t _f | | - | 10 | - | nS |
| Total Gate Charge | Qg |)/ <u>40)/</u>] 0.54 | - | 9 | - | nC |
| Gate-Source Charge | Q _{gs} | V_{DS} =-10V,I _D =-2.5A, | - | 1.0 | - | nC |
| Gate-Drain Charge | Q _{gd} | V_{GS} =-4.5V | - | 2.5 | _ | nC |
| Drain-Source Diode Characteristics | | | | | | |
| Diode Forward Voltage (Note 3) | V _{SD} | V_{GS} =0V,I _S =-3.0A | - | - | -1.2 | V |
| Diode Forward Current (Note 2) | I _S | | - | - | -3.0 | Α |

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, t \leq 10 sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production



NCE2301A



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Typical Electrical and Thermal Characteristics

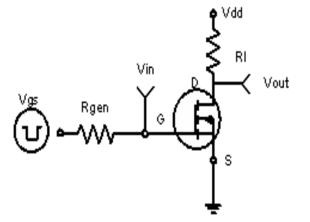
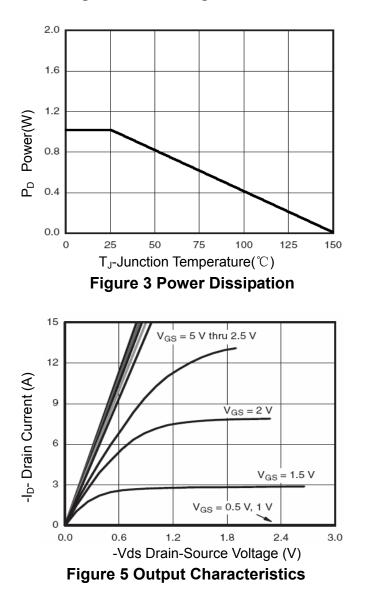
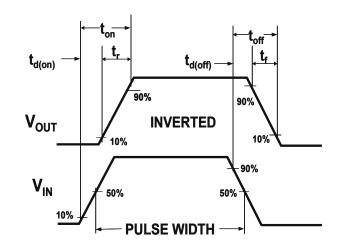
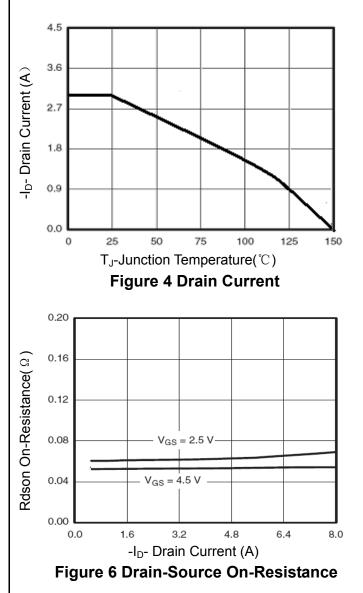


Figure 1:Switching Test Circuit





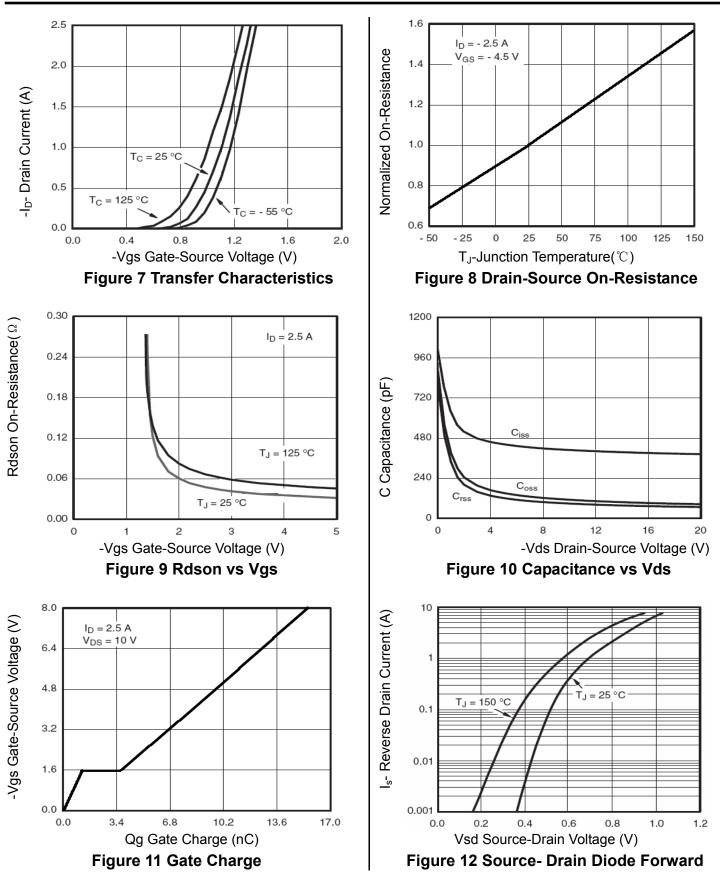








NCE2301A







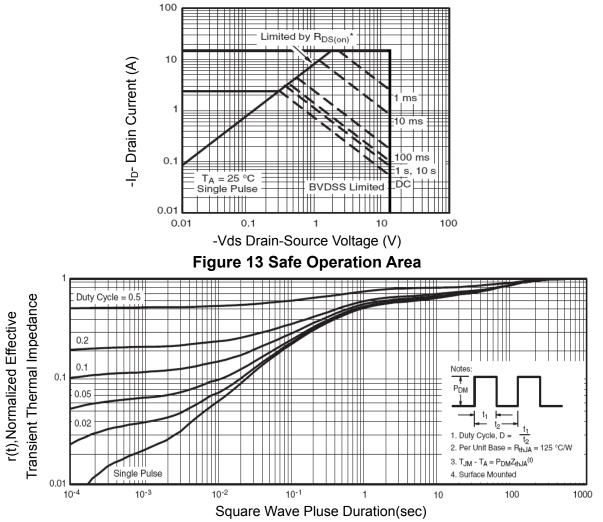
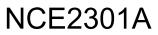
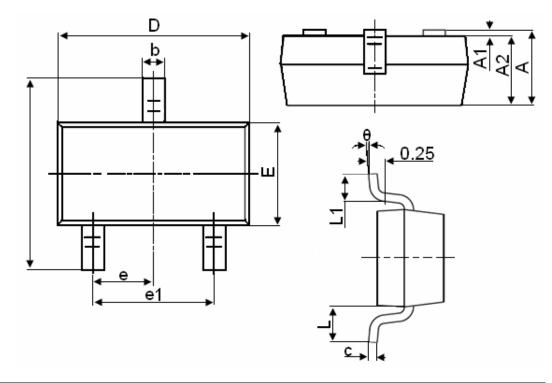


Figure 14 Normalized Maximum Transient Thermal Impedance





SOT-23 Package Information



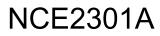
| Symbol | | Dimensions in Millimeters | |
|--------|----------|---------------------------|--|
| Symbol | MIN. | MAX. | |
| A | 0.900 | 1.150 | |
| A1 | 0.000 | 0.100 | |
| A2 | 0.900 | 1.050 | |
| b | 0.300 | 0.500 | |
| с | 0.080 | 0.150 | |
| D | 2.800 | 3.000 | |
| E | 1.200 | 1.400 | |
| E1 | 2.250 | 2.550 | |
| е | | 0.950TYP | |
| e1 | 1.800 | 2.000 | |
| L | 0.550REF | | |
| L1 | 0.300 | 0.500 | |
| θ | 0° | 8° | |

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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